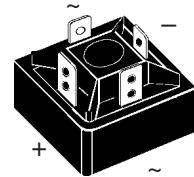
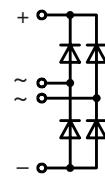


Single Phase Rectifier Bridge

Standard and Avalanche Types

V_{RSM}	V_{BRmin} ①	V_{RRM}	Standard	Avalanche
V	V	V	Types	Types
900		800	VBO 25-08NO2	
1300	1230	1200	VBO 25-12NO2	VBO 25-12AO2
1500	1430	1400	VBO 25-14NO2	VBO 25-14AO2
1700	1630	1600	VBO 25-16NO2	VBO 25-16AO2

① For Avalanche Types only



Symbol	Test Conditions		Maximum Ratings		
I_{dAV} ②	$T_c = 85^\circ\text{C}$, module		38	A	
I_{dAVM}	module		40	A	
P_{RSM}	$T_{VJ} = T_{VJM}$	$t = 10 \mu\text{s}$	3.4	kW	
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $V_R = 0$	$t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	370	A	
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	390	A	
I^{2t}	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	320	A	
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	340	A	
T_{VJ}			-40...+150	$^\circ\text{C}$	
T_{VJM}			150	$^\circ\text{C}$	
T_{stg}			-40...+125	$^\circ\text{C}$	
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ min}$ $t = 1 \text{ s}$	3000	V~	
			3600	V~	
M_d	Mounting torque (M5) (10-32 UNF)		1.5-2	Nm	
			13-18	lb.in.	
Weight	typ.		15	g	

Symbol	Test Conditions		Characteristic Values		
I_R	$V_R = V_{RRM};$ $V_R = V_{RRM};$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = T_{VJM}$	\leq	0.3	mA
			\leq	5	mA
V_F	$I_F = 55 \text{ A};$	$T_{VJ} = 25^\circ\text{C}$	\leq	1.36	V
V_{TO}	For power-loss calculations only		0.85	V	
r_T	$T_{VJ} = T_{VJM}$		8	$\text{m}\Omega$	
R_{thJC}	per diode, DC current		2.8	K/W	
	per module		0.7	K/W	
R_{thJK}	per diode, DC current		3.2	K/W	
	per module		0.8	K/W	
d_s	Creeping distance on surface		13	mm	
d_A	Creepage distance in air ③		9.5	mm	
a	Max. allowable acceleration		50	m/s^2	

Data according to IEC 60747 and refer to a single diode unless otherwise stated
② for resistive load at bridge output, ③ with isolated fast-on tabs.

IXYS reserves the right to change limits, test conditions and dimensions.

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$I_{dAV} = 38 \text{ A}$
 $V_{RRM} = 800-1600 \text{ V}$

Features

- Avalanche rated parts available
- Package with DCB ceramic base plate
- Isolation voltage 3600 V~
- Planar passivated chips
- Low forward voltage drop
- 1/4" fast-on terminals
- UL registered E 72873

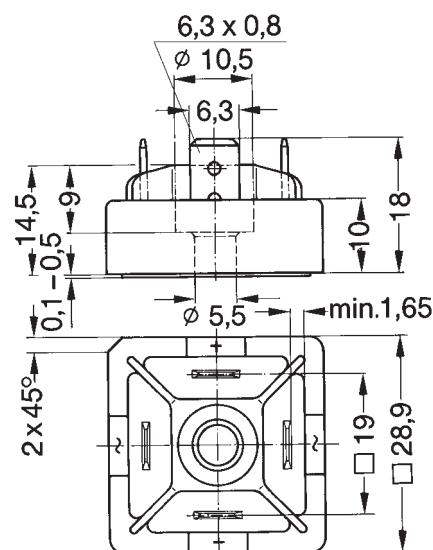
Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature and power cycling

Dimensions in mm (1 mm = 0.0394")



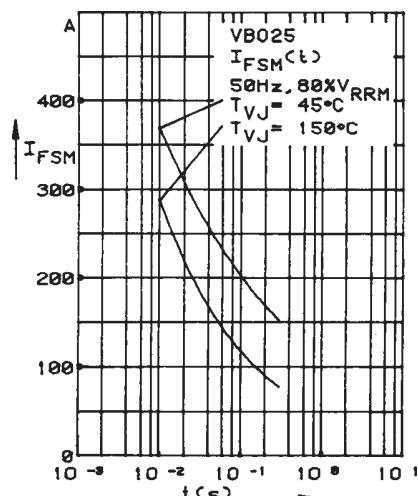


Fig. 1 Surge overload current per diode
I_{FSM}: Crest value, t: duration

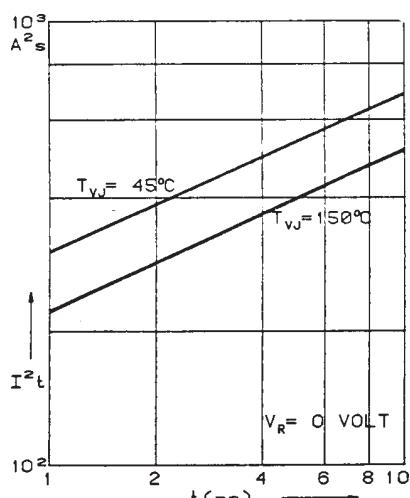


Fig. 2 I^2t versus time (1-10 ms)
per diode

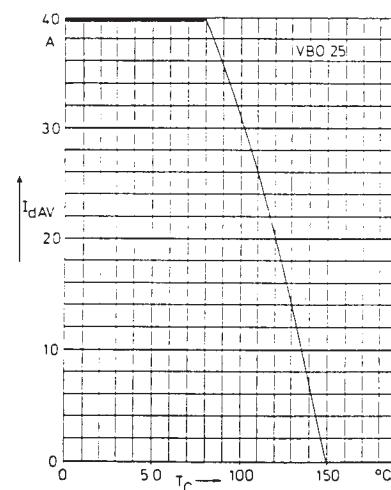


Fig. 3 Max. forward current at case temperature

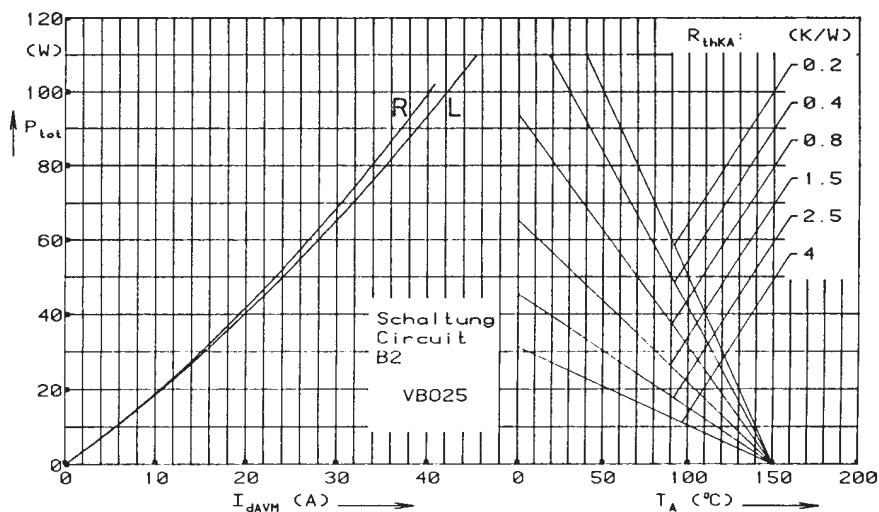


Fig. 4 Power dissipation versus direct output current and ambient temperature

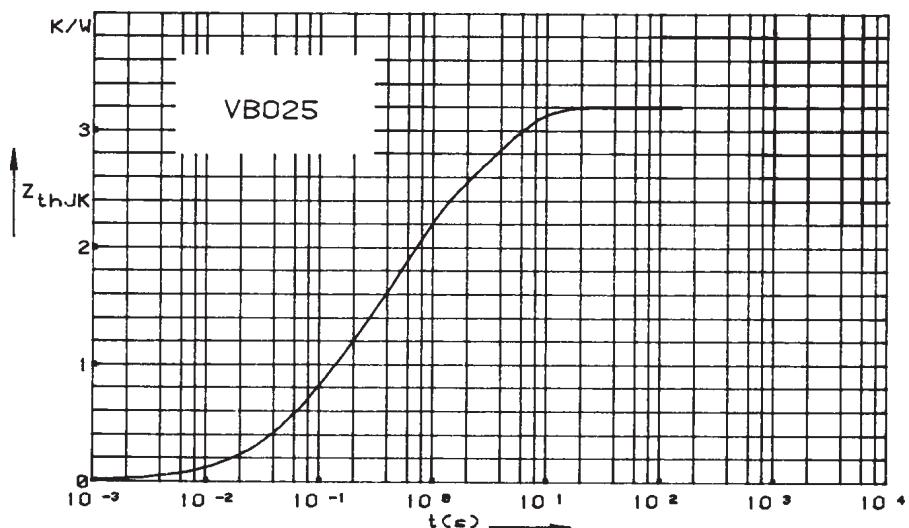


Fig. 5 Transient thermal impedance junction to heatsink per diode

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Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.775	0.0788
2	1.390	0.504
3	1.055	3.701